

# RMPA0951-102

## 3V Cellular CDMA Power Amplifier Module

## ADVANCED INFORMATION

### Description

The RMPA0951-102 is a dual mode, small-outline power amplifier module (PAM) for Cellular CDMA personal communication system applications. The PA is internally-matched to 50 ohms and DC blocked which minimizes the use of external components and reduces circuit complexity for system designers. High AMPS/CDMA efficiency and good linearity are achieved using Raytheon's Heterojunction Bipolar Transistor (HBT) process.

## Features

- ◆ Single positive-supply operation.
- ◆ High dual-mode (AMPS/CDMA) efficiency and good linearity
- ◆ Small size: 6.0 x 6.0 x 1.5 mm<sup>3</sup> LCC package.
- ◆ 50-ohm matched input and output module.
- ◆ Adjustable quiescent current and power-down mode.



### Absolute Maximum Ratings<sup>1</sup>

Parameter	Symbol	Min	Typical	Max	Units
Supply Voltage	Vc1, Vc2		3.5	6.0	V
Reference Voltage	Vref	1.5	3.0	4.0	V
RF Input Power <sup>2</sup>	Pin		-3/+2	+7	dBm
Load VSWR	VSWR		1.2:1	10:1	
Case Operating Temperature	Tc	-40	+25	+110	°C
Storage Temperature	Tstg	-55	+25	+150	°C

## Electrical Characteristics<sup>3</sup>

Parameter	Min	Typ	Max	Unit
Frequency Range	824		849	MHz
CDMA Gain (Pout=0 dBm) (Pout=+28 dBm)		29.5 31		dB dB
Analog Output Power	31.5			dBm
AMPS Gain (Pout=+31.5 dBm)		29		
Power-Added Efficiency				
CDMA (Pout =+28 dBm)		32		%
Analog (Pout =+31.5 dBm)		46		%
ACPR (Pout=+28 dBm) <sup>5</sup>		-49		dBc
Noise Figure		5	6	dB

Parameter	Min	Typ	Max	Unit
Rx-Band Noise Power (All Power Levels)			-135	dBm/Hz
Input VSWR (50Ω)		2.0:1	2.5:1	---
Output VSWR (50Ω)		3.5:1		---
Stability (All spurious) <sup>4</sup>			-70	dBc
Harmonics (Po ≤ 28 dBm) 2fo, 3fo, 4fo			-30	dBc
Quiescent Current		70	100	mA
Power Shutdown Current <sup>6</sup>		2	10	μA
Vcc	3.0	3.5	4.0	Volts
Vref	2.0	3.0	3.2	Volts
Case Operating Temp	-30		+85	°C

**Notes:**

1. No permanent damage with only one parameter set at extreme limit. Other parameters at typical values.
2. Typical RF input power for +28 dBm CDMA (-3 dBm) and +31.5 dBm AMPS-Mode output powers.
3. All parameters to be met at  $T_a = +25^{\circ}\text{C}$ ,  $V_{cc} = +3.5\text{V}$ ,  $V_{ref}=3.0\text{V}$  and load  $VSWR \leq 1.2:1$ .
4. Load  $VSWR \leq 6:1$  all phase angles.
5. CDMA Waveform measured using the ratio of the average power within the 1.23 MHz signal channel to the power within a 30 kHz resolution bandwidth at a 885 KHz offset.
6. No applied RF signal.  $V_{cc}=+3.5\text{V}$  nominal.  $V_{ref}=+0.2\text{V}$  maximum.

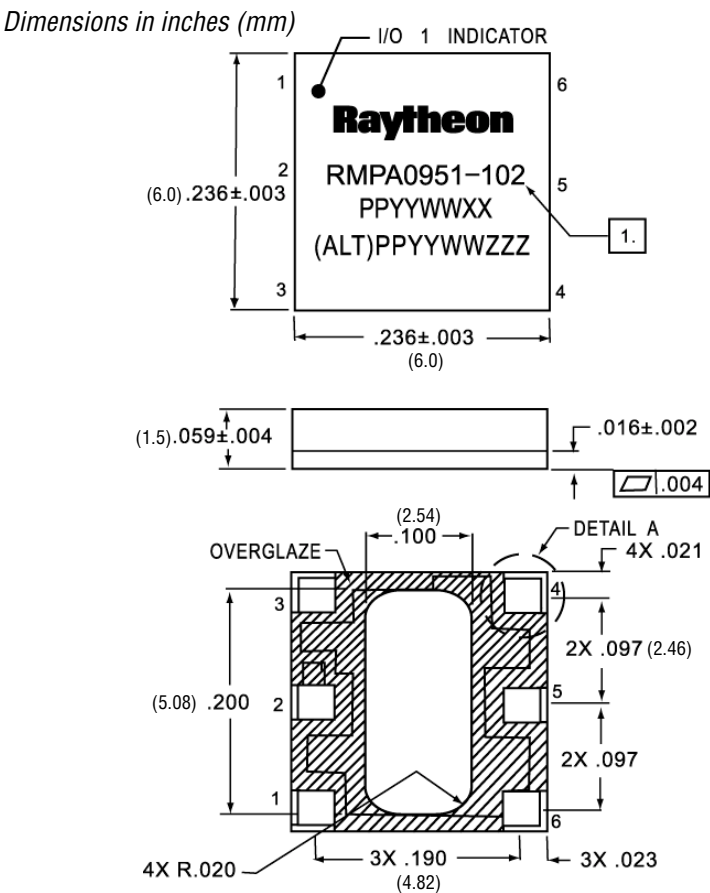
**Characteristic performance data and specifications are subject to change without notice.**

# RMPA0951-102

## 3V Cellular CDMA Power Amplifier Module

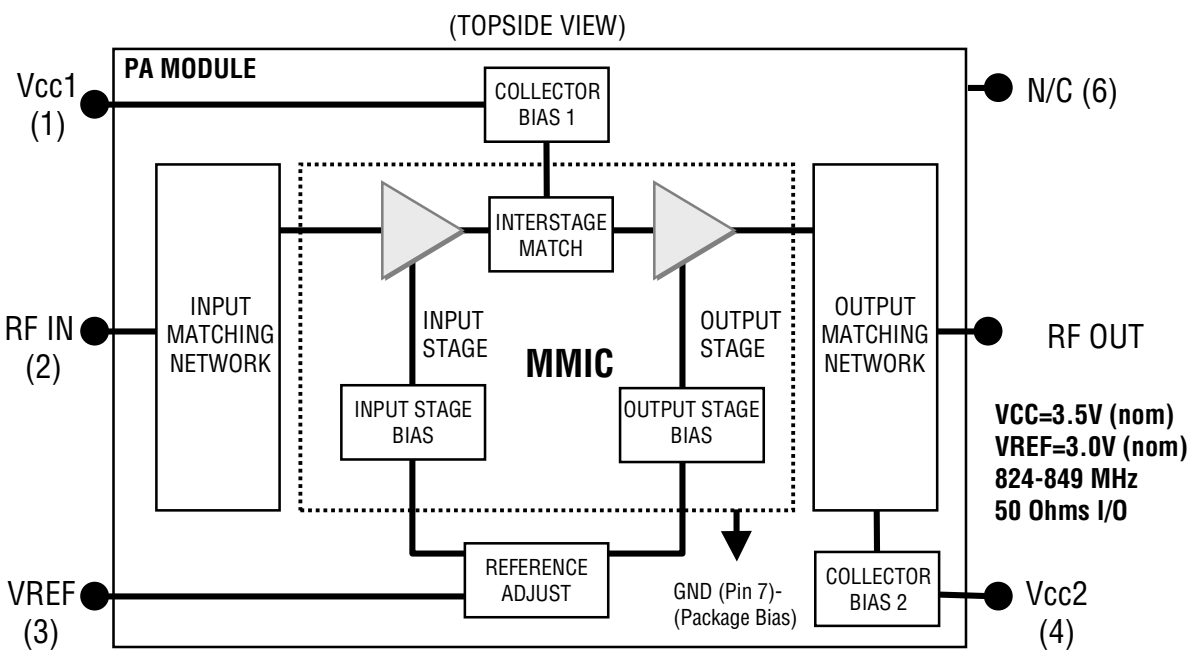
ADVANCED INFORMATION

Package Information



Pin #	Description
1	Vcc1
2	RF IN
3	VREF
4	Vcc2
5	RF OUT
6	N/C
7	GND

Functional Block Diagram



Characteristic performance data and specifications are subject to change without notice.

# RMPA0951-102

## 3V Cellular CDMA Power Amplifier Module

ADVANCED INFORMATION

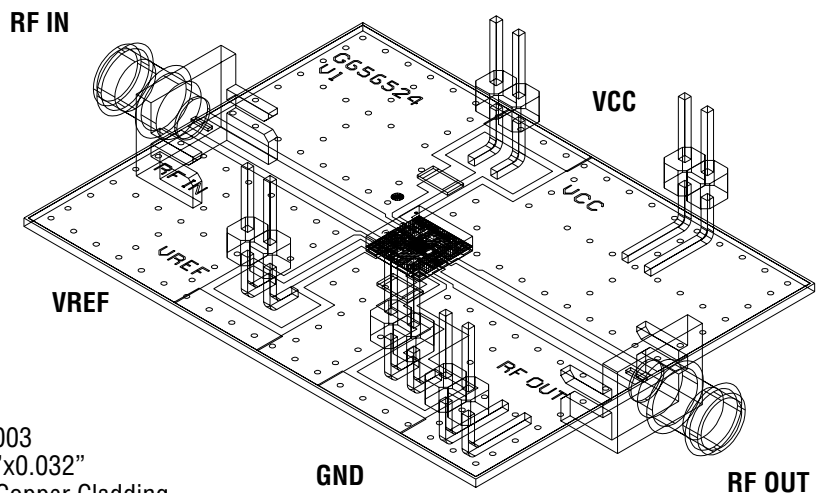
### Evaluation Board Layout, Schematic, and Instructions

With device marking oriented right side up, RF IN is on the left and RF OUT is on the right.

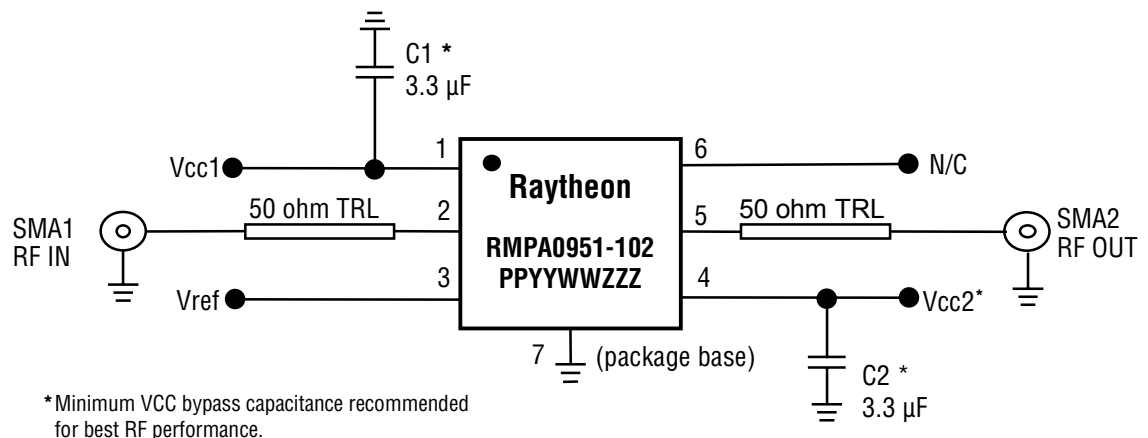
VCC= +3.5V nominal. Vref=+ 3.0V nominal to obtain Iccq= 70 mA. Operation at lower or higher quiescent currents can be achieved by decreasing or increasing Vref voltage relative to +3.0V.

First ground the PCB (GND terminal) and apply +3.5V to the collector supply terminals (VCC1, VCC2). Next apply +3.0V to the reference supply (VREF terminal). Quiescent collector current with no RF applied will be about 80 mA. Reference supply current with or without RF applied will be about 15 mA. When turning amplifier off, reverse power supply sequence.

Apply -20 dBm RF input power at Cellular frequency (824-849 MHz). After making any initial small signal measurements at this drive level, input power may be increased up to a maximum of +7 dBm for large signal, analog (AMPS) or digital CDMA measurements. Do not exceed +7 dBm input power.



PCB Specifications:  
Material: Rogers R04003  
Dimensions: 2.0"x1.5"x0.032"  
Metallization: 1/2 OZ Copper Cladding



Characteristic performance data and specifications are subject to change without notice.

# RMPA0951-102

## 3V Cellular CDMA Power Amplifier Module

ADVANCED INFORMATION

### Application Information

#### ◆ Precautions to Avoid Permanent Device Damage:

- Cleanliness: Observe proper handling procedures to ensure clean devices and PCBs. Devices should remain in their original packaging until component placement to ensure no contamination or damage to RF, DC & ground contact areas.
- Device Cleaning: Standard board cleaning techniques should not present device problems provided that the boards are properly dried to remove solvents or water residues.
- Static Sensitivity: Follow ESD precautions to protect against ESD damage:
  - A properly grounded static-dissipative surface on which to place devices.
  - Static-dissipative floor or mat.
  - A properly grounded conductive wrist strap for each person to wear while handling devices.
- General Handling: Handle the package on the top with a vacuum collet or along the edges with a sharp pair of bent tweezers. Avoiding damaging the RF, DC, & ground contacts on the package bottom. Do not apply excessive pressure to the top of the lid.
- Device Storage: Devices are supplied in heat-sealed, moisture-barrier bags. In this condition, devices are protected and require no special storage conditions. Once the sealed bag has been opened, devices should be stored in a dry nitrogen environment.

#### ◆ Device Usage: Raytheon recommends the following procedures prior to assembly.

- Dry-bake devices at 125°C for 24 hours minimum. Note: The shipping trays cannot withstand 125°C baking temperature.
- Assemble the dry-baked devices within 7 days of removal from the oven.
- During the 7-day period, the devices must be stored in an environment of less than 60% relative humidity and a maximum temperature of 30°C
- If the 7-day period or the environmental conditions have been exceeded, then the dry-bake procedure must be repeated.

#### ◆ Solder Materials & Temperature Profile: Reflow soldering is the preferred method of SMT attachment. Hand soldering is not recommended.

##### – Reflow Profile

- Ramp-up: During this stage the solvents are evaporated from the solder paste. Care should be taken to prevent rapid oxidation (or paste slump) and solder bursts caused by violent solvent out-gassing. A typical heating rate is 1- 2°C/sec.
- Pre-heat/soak: The soak temperature stage serves two purposes; the flux is activated and the board and devices achieve a uniform temperature. The recommended soak condition is: 120-150 seconds at 150°C.
- Reflow Zone: If the temperature is too high, then devices may be damaged by mechanical stress due to thermal mismatch or there may be problems due to excessive solder oxidation. Excessive time at temperature can enhance the formation of inter-metallic compounds at the lead/board interface and may lead to early mechanical failure of the joint. Reflow must occur prior to the flux being completely driven off. The duration of peak reflow temperature should not exceed 10 seconds. Maximum soldering temperatures should be in the range 215-220°C, with a maximum limit of 225°C.
- Cooling Zone: Steep thermal gradients may give rise to excessive thermal shock. However, rapid cooling promotes a finer grain structure and a more crack-resistant solder joint. Figure 1 indicates the recommended soldering profile.

#### ◆ Solder Joint Characteristics: Proper operation of this device depends on a reliable void-free attachment of the heatsink to the PWB. The solder joint should be 95% void-free and be a consistent thickness.

#### ◆ Rework Considerations: Rework of a device attached to a board is limited to reflow of the solder with a heat gun. The device should not be subjected to more than 225°C and reflow solder in the molten state for more than 5 seconds. No more than 2 rework operations should be performed.

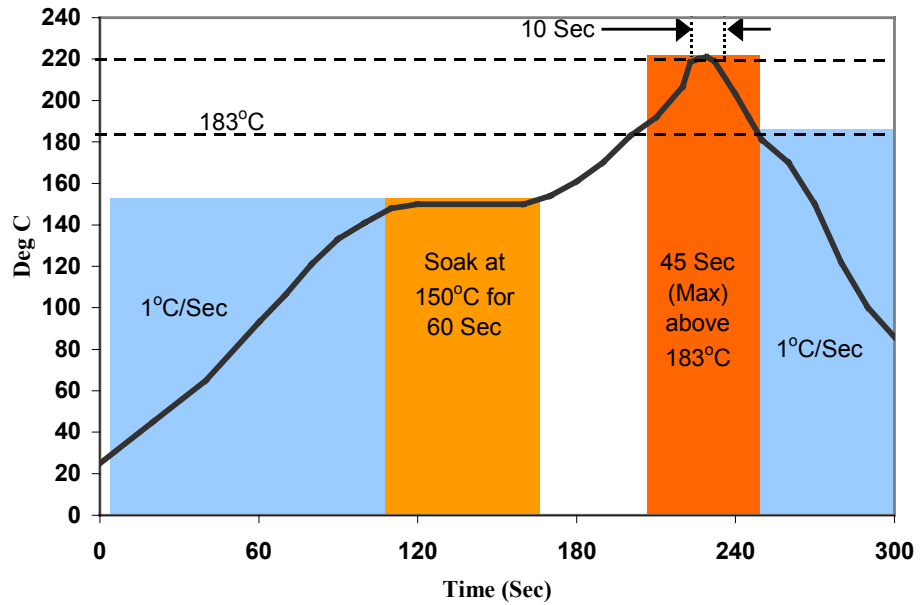
Characteristic performance data and specifications are subject to change without notice.

# RMPA0951-102

## 3V Cellular CDMA Power Amplifier Module

ADVANCED INFORMATION

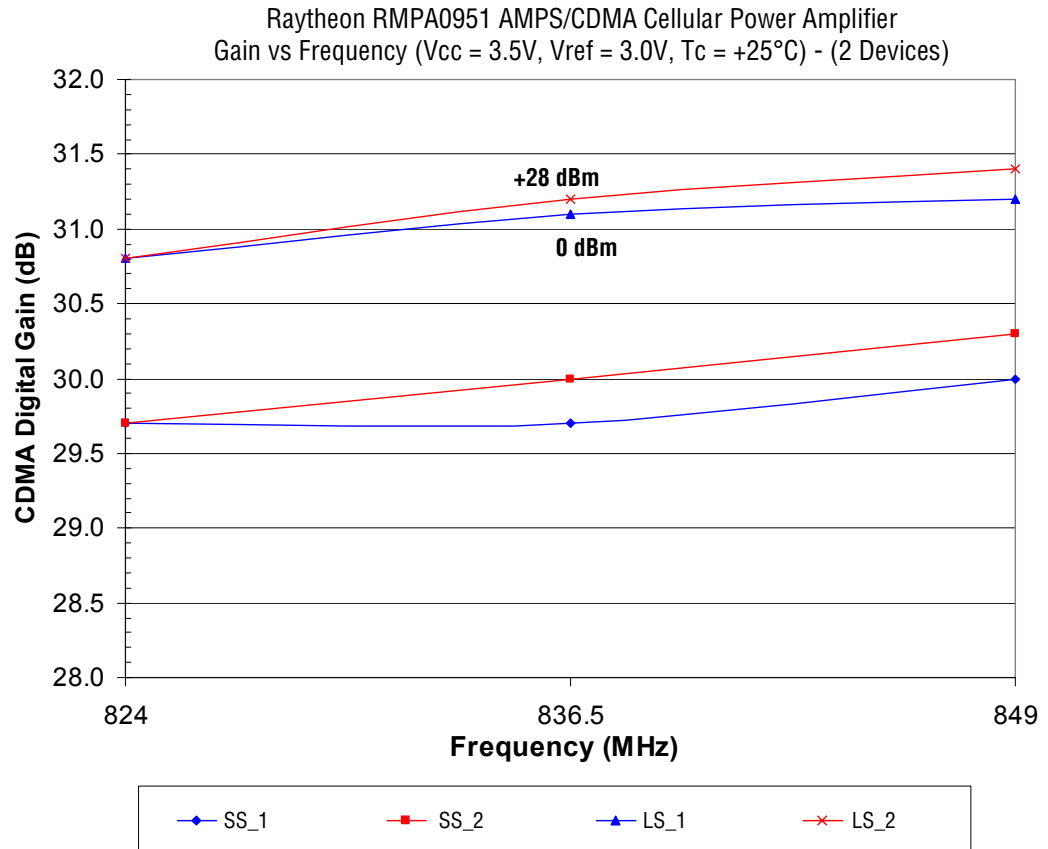
**Figure 1**  
Recommended Solder  
Reflow Profile



### Performance Data

Measured performance for typical production amplifiers is represented in the figures below. Key characteristics such as gain, efficiency, output power and linearity are shown for both AMPS and CDMA operation.

**Figure 2**  
CDMA Small-Signal and  
Large-Signal Gain



Characteristic performance data and specifications are subject to change without notice.

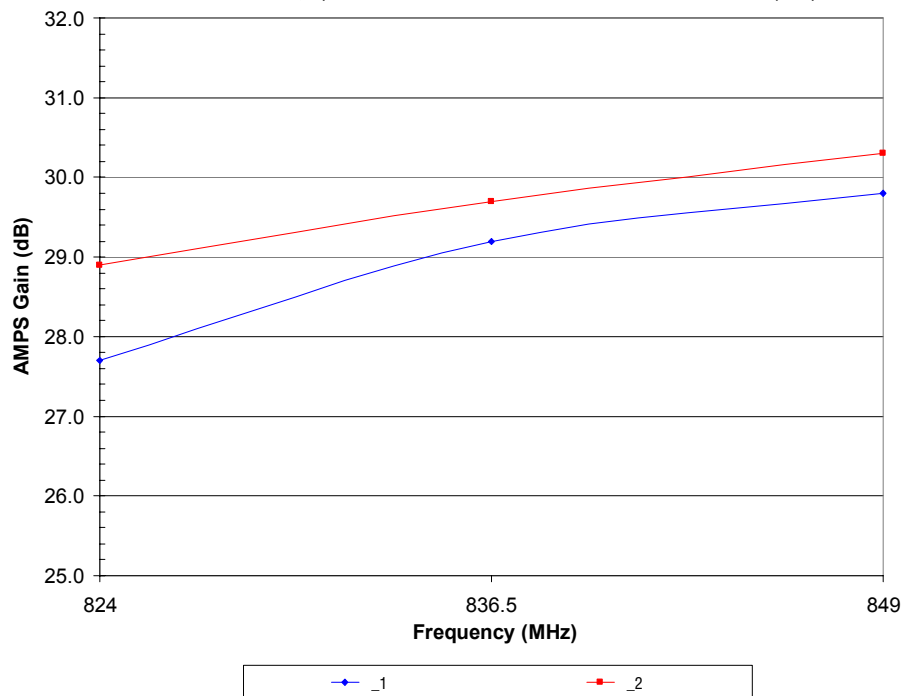
# RMPA0951-102

## 3V Cellular CDMA Power Amplifier Module

ADVANCED INFORMATION

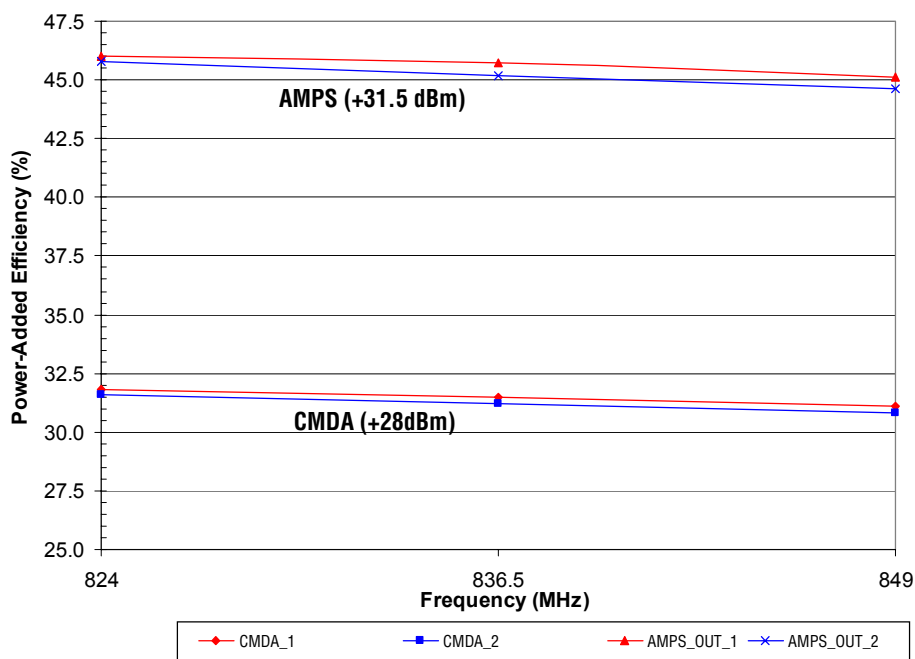
**Figure 3**  
AMPS/Analog-Mode  
(+31.5 dBm) Large-  
Signal Gain

Raytheon RMPA0951 AMPS/CDMA Power Amplifier  
AMPS-Mode Gain vs Frequency (Vcc = 3.5V, Vref = 3.0V, Pout = +31.5 dBm) - (2 Devices)



**Figure 4**  
CDMA (+28 dBm) and  
AMPS-Mode (+31.5 dBm)  
Power-Added Efficiency

Raytheon RMPA0951 AMPS/CDMA Power Amplifier  
AMPS-Mode and CDMA PAE Vcc = 3.5V, Vref = 3.0V, Tc = +25°C) - (2 Devices)



Characteristic performance data and specifications are subject to change without notice.

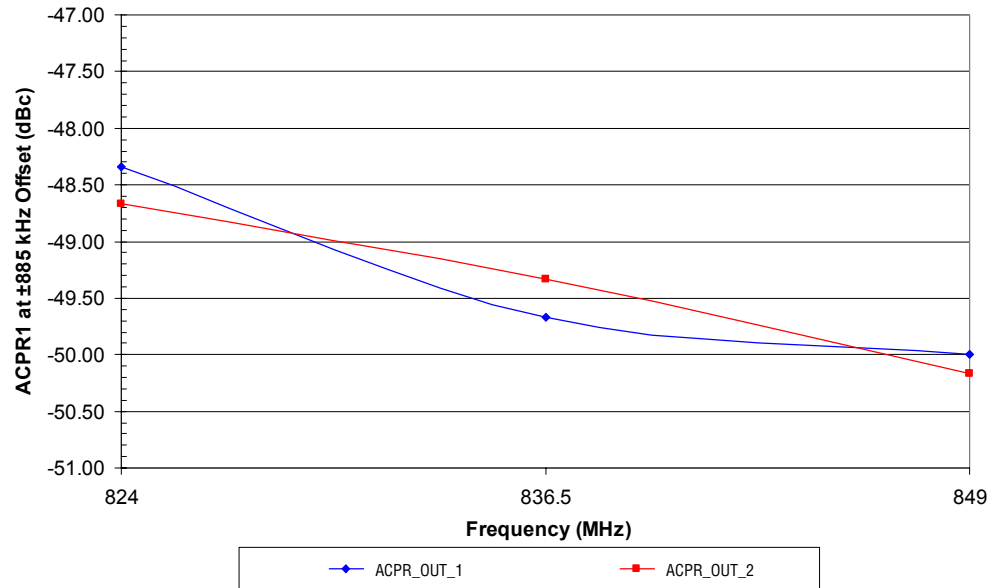
# RMPA0951-102

## 3V Cellular CDMA Power Amplifier Module

ADVANCED INFORMATION

**Figure 5**  
Adjacent-Channel Power  
Rejection (Pout = +28  
dBm) at ±885 kHz Offset

Raytheon RMPA0951 AMPS/CDMA Cellular Power Amplifier  
ACPR vs Frequency (Vcc = 3.5V, Vref = 3.0V, Offset: ±885 kHz, Ta = +25°C) - (2 Devices)



Characteristic performance data and specifications are subject to change without notice.

# Worldwide Sales Representatives

## North America

**D&L Technical Sales**  
6139 S. Rural Road, #102  
Tempe, AZ 85283  
480-730-9553  
fax: 480-730-9647  
Nicholas Delvecchio, Jr.  
dlarizona@aol.com

**Hi-Peak Technical Sales**  
P.O. Box 6067  
Amherst, NH 03031  
866-230-5453  
fax: 603-672-9228  
sales@hi-peak.com

**Spartech South**  
2115 Palm Bay Road, NE,  
Suite 4  
Palm Bay, FL 32904  
321-727-8045  
fax: 321-727-8086  
Jim Morris  
jim@spartech-south.com

**TEQ Sales, Inc.**  
920 Davis Road, Suite 304  
Elgin, IL 60123  
847-742-3767  
fax: 847-742-3947  
Dennis Culpepper  
dculpepper@teqsales.com

**Cantec Representatives**  
8 Strathearn Ave, No. 18  
Brampton, Ontario  
Canada L6T 4L9  
905-791-5922  
fax: 905-791-7940  
Dave Batten  
cantec-ott@cantec-o.net

**Steward Technology**  
6990 Village Pkwy #206  
Dublin, CA 94568  
925-833-7978  
fax: 925-560-6522  
John Steward  
johnsteward1@msn.com

## Europe

**Sangus OY**  
Lunkintie 21,  
90460 Oulunsalo  
Finland  
358-8-8251-100  
fax: 358-8-8251-110  
Juha Virtala  
juha.virtala@sangus.fi

**Sangus AB**  
Berghamnvgen 68  
Box 5004  
S-165 10 Hasselby  
Sweden  
Ronny Gustafson  
468-0-380210  
fax: 468-0-3720954

**Globes Elektronik & Co.**  
Klarastrabe 12  
74072 Heilbronn  
Germany  
49-7131-7810-0  
fax: 49-7131-7810-20  
Ulrich Blievernicht  
hfwelt@globes.de

**MTI Engineering Ltd.**  
Afek Industrial Park  
Hamelacha 11  
New Industrial Area  
Rosh Hayin 48091  
Israel  
972-3-902-5555  
fax: 972-3-902-5556  
Adi Peleg  
adi\_p@mti-group.co.il

**Sirces srl**  
Via C. Boncompagni, 3B  
20139 Milano  
Italy  
3902-57404785  
fax: 3902-57409243  
Nicola Iacovino  
nicola.iacovino@sirces.it

## Asia

**ITX Corporation**  
2-5, Kasumigaseki  
3-Chome  
Chiyoda-Ku  
Tokyo 100-6014 Japan  
81-3-4288-7073  
fax: 81-3-4288-7243  
Maekawa Ryosuke  
maekawa.ryosuke@  
itx-corp.co.jp

**Sea Union**  
9F-1, Building A, No 19-3  
San-Chung Road  
Nankang Software Park  
Taiwan, ROC  
Taipei 115  
02-2655-3989  
fax: 02-2655-3918  
Murphy Su  
murphy@seaunionweb.com.tw

## Worldwide Distribution

**Headquarters**  
6321 San Ignacio Drive  
San Jose, CA 95119  
408-360-4073  
fax: 408-281-8802  
Art Herbig  
art.herbig@avnet.com

**Belgium and Luxembourg**  
Cipalstraat  
2440 GEEL  
Belgium  
32 14 570670  
fax: 32 14 570679  
sales.be@bfiophtilas.avnet.com

**United Kingdom**  
Burnt Ash Road  
Aylesford, Kent  
England  
ME207XB  
44 1622882467  
fax: 44 1622882469  
rfsales.uk@  
bfiophtilas.avnet.com

**France**  
4 Allee du Cantal  
Evry, Cedex  
France  
33 16079 5900  
fax: 33 16079 8903  
sales.fr@  
bfiophtilas.avnet.com

**Holland**  
Chr. Huygensweg 17  
2400 AJ ALPHEN AAN DEN  
RIJN  
The Netherlands  
31 172 446060  
fax: 33 172 443414  
sales.nl@  
bfiophtilas.avnet.com

**Spain**  
C/Isobel Colbrand, 6 - 4a  
28050 Madrid  
Spain  
34 913588611  
fax: 34 913589271  
sales.es@  
bfiophtilas.avnet.com

## Sales Office Headquarters

**United States  
(East Coast)**  
Raytheon  
362 Lowell Street  
Andover, MA 01810  
978-684-8628  
fax: 978-684-8646  
Walter Shelmet  
wshelmet@  
rrfc.raytheon.com

**United States  
(West Coast)**  
Raytheon  
362 Lowell Street  
Andover, MA 01810  
978-684-8919  
fax: 978-684-8646  
Rob Sinclair  
robert\_w\_sinclair@  
rrfc.raytheon.com

**Europe**  
Raytheon  
AM Teckenberg 53  
40883 Ratingen  
Germany  
49-2102-706-155  
fax: 49-2102-706-156  
Peter Hales  
peter\_j\_hales@  
raytheon.com

**Asia**  
Raytheon  
Room 601, Gook Je Ctr. Bldg  
191 Hangang Ro 2-GA  
Yongsan-Gu, Seoul,  
Korea 140-702  
82-2-796-5797  
fax: 82-2-796-5790  
T.G. Lee  
tg\_lee@  
rrfc.raytheon.com

## Customer Support

978-684-8900

fax: 978-684-5452

customer\_support@rrfc.raytheon.com